

HD74HC173

4-bit D-type Register (with 3-state outputs)

REJ03D0583-0200 (Previous ADE-205-459) Rev.2.00 Oct 11, 2005

Description

The four D type Flip-Flops operate synchronously from a common clock. The 3-state outputs allow the device to be used in bus organized systems. The outputs are placed in the 3-stage mode when either of the output disable pins are in the logic high level.

The input disable allows the flip-flops to remain in their present states without having to disrupt the clock. If either of the 2 input disables are taken to a logic high level, the Q outputs are fed back to the inputs, forcing the flip-flops to remain in the same state. Clearing is enabled by taking the clear input to a logic high level. The data outputs change state on the positive going edge of the clock.

Features

• High Speed Operation: t_{pd} (Clock to Q) = 14 ns typ ($C_L = 50 \text{ pF}$)

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage: $V_{CC} = 2 \text{ to } 6 \text{ V}$

• Low Input Current: 1 μA max

• Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC173P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	Р	_
HD74HC173FPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)
HD74HC173RPEL	SOP-16 pin (JEDEC)	PRSP0016DG-A (FP-16DNV)	RP	EL (2,500 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

		Data I	Enable		
Clear	Clock	G ₁	G ₂	Data D	Output Q
Н	Х	Х	Х	Х	L
L	L	X	X	Х	Q_0
L		Н	X	Х	Q ₀
L		X	Н	Х	Q_0
L		L	L	L	L
L		L	L	Н	Н

Note: When either M or N (or both) is (are) high the output is disabled to the high-impedance state; however sequential operation of the flip-flops is not affected.

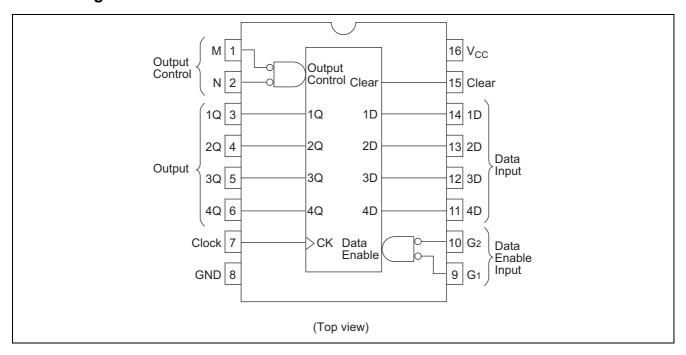
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Q_{Ao} to Q_{Ho} = Outputs remain unchanged.

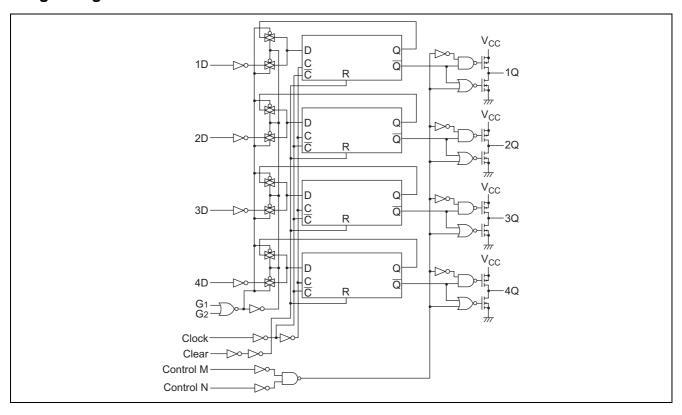
 Q_{An} to Q_{Gn} = Data shifted from the previous stage on a positive edge at the clock input.

H: High levelL: Low levelX: Irrelevant

Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
Input / Output voltage	Vin, Vout	-0.5 to V _{CC} +0.5	V
Input / Output diode current	I _{IK} , I _{OK}	±20	mA
Output current	I ₀	±35	mA
V _{CC} , GND current	I _{CC} or I _{GND}	±75	mA
Power dissipation	P _T	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	2 to 6	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V _{CC}	V	
Operating temperature	Та	-40 to 85	°C	
		0 to unlimited		V _{CC} = 2.0 V
Input rise / fall time*1	t _r , t _f	0 to unlimited	ns	$V_{CC} = 4.5 \text{ V}$
		0 to unlimited		V _{CC} = 6.0 V

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

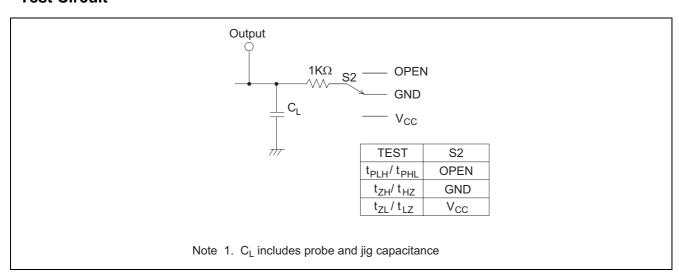
Electrical Characteristics

			Ta = 25°C		Ta = -40 to+85°C					
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit	Test Cor	nditions
Input voltage	V _{IH}	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	_	_	3.15	_			
		6.0	4.2	_	_	4.2	_			
	V _{IL}	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35			
		6.0	_	_	1.8	_	1.8			
Output voltage	V _{OH}	2.0	1.9	2.0	_	1.9	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20 \mu A$
		4.5	4.4	4.5	_	4.4	_			
		6.0	5.9	6.0	_	5.9	_			
		4.5	4.18	_	_	4.13	_			$I_{OH} = -6 \text{ mA}$
		6.0	5.68	_	_	5.63	_			$I_{OH} = -7.8 \text{ mA}$
	V _{OL}	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 20 \mu A$
		4.5	_	0.0	0.1	_	0.1			
		6.0	_	0.0	0.1	_	0.1			
		4.5	_	_	0.26	_	0.33			I _{OL} = 6 mA
		6.0	_	_	0.26	_	0.33			$I_{OL} = 7.8 \text{ mA}$
Off-state output	l _{OZ}	6.0	_	_	±0.5		±5.0	μΑ	$Vin = V_{IH} or V_{IL}$	
current									Vout = V_{CC} or G	ND
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	$Vin = V_{CC} \text{ or } GN$	ID
Quiescent supply	I _{CC}	6.0	_	_	4.0	_	40	μΑ	$Vin = V_{CC} \text{ or } GN$	ID, lout $= 0 \mu A$
current										

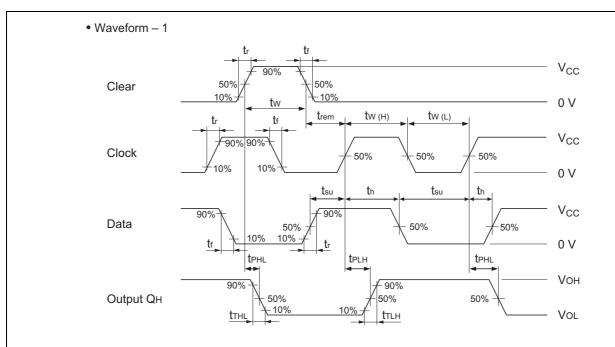
Switching Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

			Т	a = 25°	С	Ta = -40	to +85°C		
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Maximum clock	f _{max}	2.0		_	5	_	4	MHz	
frequency		4.5		_	27	_	21		
		6.0		_	32	_	25		
Propagation delay	t _{PLH} , t _{PHL}	2.0		_	175	_	220	ns	Clock to Q
time		4.5		14	35	_	44		
		6.0		_	30	_	37		
	t _{PHL}	2.0		_	150	_	190	ns	Clear to Q
		4.5	1	14	30	_	38		
		6.0		_	26	_	33		
Enable time	t_{ZH}, t_{ZL}	2.0	-	_	150	_	190	ns	
		4.5		12	30	_	38		
		6.0	1	_	26	_	33		
Disable time	t_{HZ}, t_{LZ}	2.0		_	150	_	190	ns	
		4.5	1	12	30	_	38		
		6.0	1	_	26	_	33		
Setup time	t _{su}	2.0	100	_	_	125	_	ns	
		4.5	20	4	_	25	_		
		6.0	17	-	_	21	_		
Removal time	t _{rem}	2.0	90	_	_	115	_	ns	
		4.5	18	0	_	23	_		
		6.0	15	_	_	20	_		
Hold time	t _h	2.0	5	_	_	5	_	ns	
		4.5	5	-2	_	5	_		
		6.0	5	_	_	5	_		
Pulse width	t _w	2.0	80	_	_	100	_	ns	
		4.5	16	4	_	20	_		
		6.0	14	_	_	17	_		
Output rise/fall	t _{TLH} , t _{THL}	2.0		_	60	_	75	ns	
time		4.5		4	12	_	15		
		6.0		_	10	_	13		
Input capacitance	Cin	_		5	10	_	10	pF	

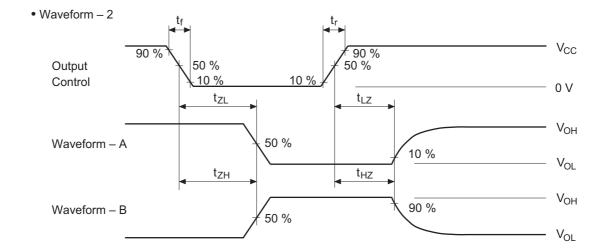
Test Circuit



Waveforms

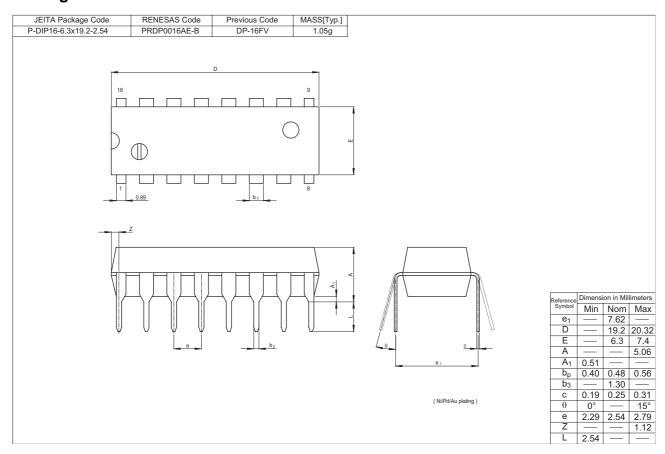


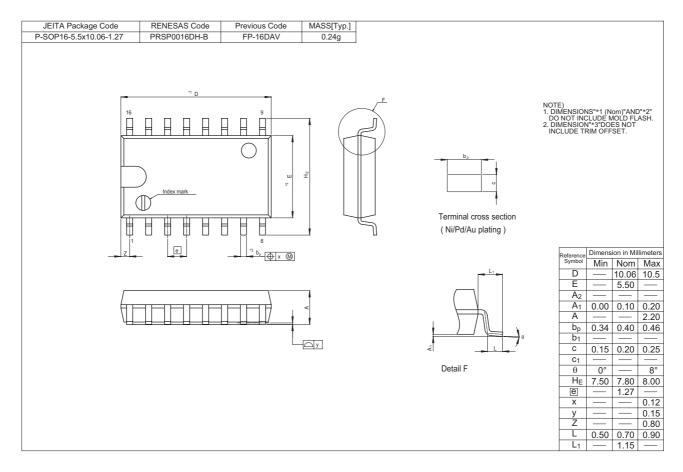
Note 1. Input pulse : PRR \leq 1 MHz, Zo = 50 Ω , $t_r \leq$ 6 ns, $t_f \leq$ 6 ns

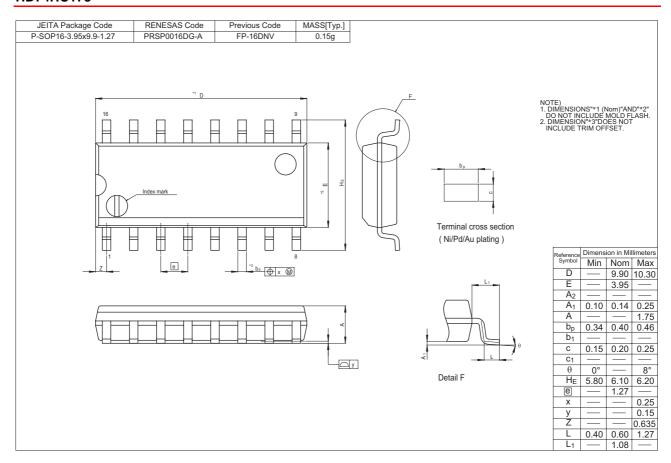


- Notes 1. Input pulse PRR \leq 1 MHz, Zo = 50 Ω , $t_r \leq$ 6 ns, $t_f \leq$ 6 ns
 - 2. Waveform A is for an output with internal conditions such that the output is low except when disabled by the output control.
 - 3. waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.

Package Dimensions







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